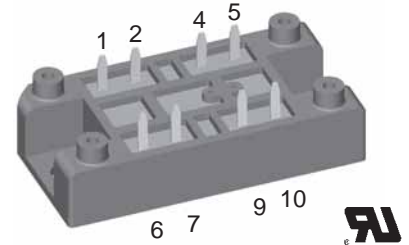
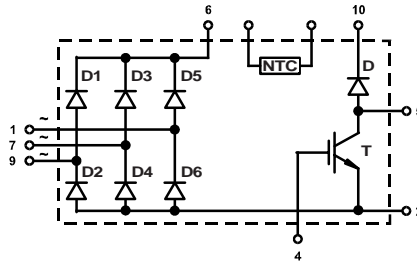


# Three Phase Rectifier Bridge with Brake Chopper

**$V_{RRM} = 1200/1600 \text{ V}$**   
 **$I_{dAVM} = 110 \text{ A}$**



### Input Rectifier D1 - D6

| Symbol     | Conditions   | Maximum Ratings |   |
|------------|--|-----------------|---|
| $V_{RRM}$  | VUB 72 -12 NO1   | 1200            | V |
|            | VUB 72 -16 NO1   | 1600            | V |
| $I_{FAV}$  | $T_C = 80^\circ\text{C}$ ; sine 180°                           | 40              | A |
| $I_{dAVM}$ | $T_C = 80^\circ\text{C}$ ; rectangular; $d = 1/3$ ; bridge     | 110             | A |
| $I_{FSM}$  | $T_{VJ} = 25^\circ\text{C}$ ; $t = 10 \text{ ms}$ ; sine 50 Hz | 530             | A |
| $P_{tot}$  | $T_C = 25^\circ\text{C}$                                       | 100             | W |

### Features

- three phase mains rectifier
- brake chopper:
  - IGBT with low saturation voltage
  - HiPerFRED™ free wheeling diode
- module package:
  - high level of integration
  - solder terminals for PCB mounting
  - UL registered E72873
  - isolated DCB ceramic base plate
  - large creepage and strike distances
  - high reliability

| Symbol     | Conditions  | Characteristic Values<br>( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified) |      |      |
|------------|---|--|------|------|
|            |   | min.   | typ. | max. |
| $V_F$      | $I_F = 25 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$  | 1.0  | 1.1  | V    |
|            |   | 0.9  |      | V    |
| $I_R$      | $V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$<br>$V_R = 0.8 \cdot V_{RRM}$ ; $T_{VJ} = 125^\circ\text{C}$ | 0.4  | 0.02 | mA   |
|            |   |  |      | mA   |
| $R_{thJC}$ | per diode   |  | 1.2  | K/W  |
| $R_{thJH}$ | with heat transfer paste  |  | 1.42 | K/W  |

### Applications

- drives with
- mains input
  - DC link
  - inverter or chopper feeding the machine
  - motor and generator/brake operation

### Chopper Diode D

| Symbol    | Conditions   | Maximum Ratings |   |
|-----------|--|-----------------|---|
| $V_{RRM}$ | $T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$ | 1200            | V |
| $I_{F25}$ | DC; $T_C = 25^\circ\text{C}$                       | 25              | A |
| $I_{F80}$ | DC; $T_C = 80^\circ\text{C}$                       | 15              | A |

| Symbol     | Conditions  | Characteristic Values |      |      |
|------------|---|-----------------------|------|------|
|            |   | min.                  | typ. | max. |
| $V_F$      | $I_F = 25 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$  | 2.7                   | 3.1  | V    |
|            |   | 2.0                   |      | V    |
| $I_R$      | $V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$<br>$T_{VJ} = 125^\circ\text{C}$   | 0.1                   | 0.1  | mA   |
|            |   |                       |      | mA   |
| $I_{RM}$   | $I_F = 15 \text{ A}$ ; $di_F/dt = -400 \text{ A}/\mu\text{s}$ ; $T_{VJ} = 125^\circ\text{C}$<br>$V_R = 600 \text{ V}$ | 16                    |      | A    |
| $t_{rr}$   |   | 130                   |      | ns   |
| $R_{thJC}$ | with heat transfer paste  |                       | 2.3  | K/W  |
| $R_{thJH}$ |   |                       | 3.12 | K/W  |

IXYS reserves the right to change limits, test conditions and dimensions.

## Chopper Transistor T

| Symbol              | Conditions   | Maximum Ratings |               |
|---------------------|--|-----------------|---------------|
| $V_{CES}$           | $T_{VJ} = 25^{\circ}\text{C}$ to $150^{\circ}\text{C}$   | 1200            | V             |
| $V_{GES}$           |  | $\pm 20$        | V             |
| $I_{C25}$           | DC; $T_C = 25^{\circ}\text{C}$   | 50              | A             |
| $I_{C80}$           | DC; $T_C = 80^{\circ}\text{C}$   | 35              | A             |
| $I_{CM}$            | $V_{GE} = \pm 15\text{ V}$ ; $R_G = 39\ \Omega$ ; $T_{VJ} = 125^{\circ}\text{C}$   | 50              | A             |
| $V_{CEK}$           | RBSOA; $L = 100\ \mu\text{H}$  | $V_{CES}$       |               |
| $t_{SC}$<br>(SCSOA) | $V_{GE} = \pm 15\text{ V}$ ; $V_{CE} = 900\text{ V}$ ; $T_{VJ} = 125^{\circ}\text{C}$<br>$R_G = 39\ \Omega$ ; non repetitive | 10              | $\mu\text{s}$ |

| Symbol   | Conditions<br>( $T_{VJ} = 25^{\circ}\text{C}$ , unless otherwise specified)  | Characteristic Values |      |          |    |
|--|--|-----------------------|------|----------|----|
|  |  | min.                  | typ. | max.     |    |
| $V_{CE(sat)}$  | $I_C = 25\text{ A}$ ; $V_{GE} = 15\text{ V}$ ; $T_{VJ} = 25^{\circ}\text{C}$<br>$T_{VJ} = 125^{\circ}\text{C}$                                     | 1.9<br>2.1            | 2.4  | V<br>V   |    |
| $V_{GE(th)}$   | $I_C = 1\text{ mA}$ ; $V_{GE} = V_{CE}$  | 4.5                   |      | 6.5 V    |    |
| $I_{CES}$  | $V_{CE} = V_{CES}$ ; $V_{GE} = 0\text{ V}$ ; $T_{VJ} = 25^{\circ}\text{C}$<br>$T_{VJ} = 125^{\circ}\text{C}$                                       | 0.1                   | 0.1  | mA<br>mA |    |
| $I_{GES}$  | $V_{CE} = 0\text{ V}$ ; $V_{GE} = \pm 20\text{ V}$   |                       | 200  | nA       |    |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$<br>$E_{on}$<br>$E_{off}$ | Inductive load, $T_{VJ} = 125^{\circ}\text{C}$<br>$V_{CE} = 600\text{ V}$ ; $I_C = 25\text{ A}$<br>$V_{GE} = \pm 15\text{ V}$ ; $R_G = 39\ \Omega$ |                       | 80   | ns       |    |
|  |  |                       |      | 50       | ns |
|  |  |                       |      | 440      | ns |
|  |  |                       |      | 50       | ns |
|  |  |                       |      | 3.8      | mJ |
|  |  |                       |      | 2.0      | mJ |
| $C_{ies}$  | $V_{CE} = 25\text{ V}$ ; $V_{GE} = 0\text{ V}$ ; $f = 1\text{ MHz}$  | 2.0                   |      | nF       |    |
| $Q_{Gon}$  | $V_{CE} = 600\text{ V}$ ; $V_{GE} = 15\text{ V}$ ; $I_C = 35\text{ A}$   | 150                   |      | nC       |    |
| $R_{thJC}$   |  |                       | 0.6  | K/W      |    |
| $R_{thJH}$   | with heat transfer paste, see mounting instructions  |                       | 1.2  | K/W      |    |

## Temperature Sensor NTC

| Symbol       | Conditions  | Characteristic Values<br>typ. |            |
|--------------|---|-------------------------------|------------|
| $R_{25}$     | $T = 25^{\circ}\text{C}$  | 2.2                           | k $\Omega$ |
| $B_{25/100}$ | $R(T) = R_{25} \cdot e^{B_{25/100} \left( \frac{1}{T} - \frac{1}{298\text{K}} \right)}$ | 100                           | K          |

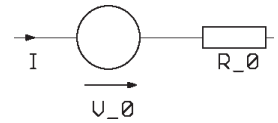
## Module

| Symbol     | Conditions   | Maximum Ratings |                    |
|------------|--|-----------------|--------------------|
| $I_{RMS}$  | per pin  | 100             | A                  |
| $T_{VJ}$   |  | -40...+150      | $^{\circ}\text{C}$ |
| $T_{stg}$  |  | -40...+125      | $^{\circ}\text{C}$ |
| $V_{ISOL}$ | $I_{ISOL} \leq 1\text{ mA}$ ; 50/60 Hz; $t = 1\text{ min}$ | 3600            | V~                 |
| $M_d$      | Mounting torque (M5)                                       | 2 - 2.5         | Nm                 |

| Symbol     | Conditions | Characteristic Values |      |      |
|------------|------------|-----------------------|------|------|
|            |            | min.                  | typ. | max. |
| $d_A, d_S$ |            | 5                     |      | mm   |
| Weight     |            |                       | 35   | g    |

## Equivalent Circuits for Simulation

### Conduction



### D1 - D6

Diode (typ. at  $T_J = 125^{\circ}\text{C}$ )

$$V_0 = 0.85\text{ V}; R_0 = 7\text{ m}\Omega$$

### T/D

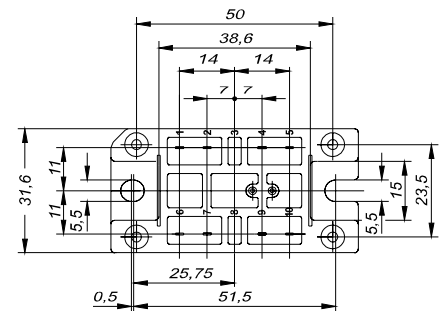
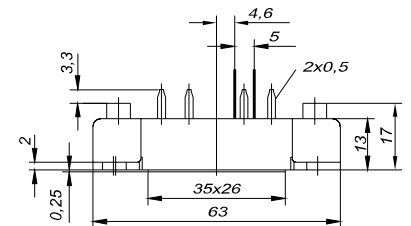
IGBT (typ. at  $V_{GE} = 15\text{ V}$ ;  $T_J = 125^{\circ}\text{C}$ )

$$V_0 = 1.0\text{ V}; R_0 = 45\text{ m}\Omega$$

Free Wheeling Diode (typ. at  $T_J = 125^{\circ}\text{C}$ )

$$V_0 = 1.25\text{ V}; R_0 = 32\text{ m}\Omega$$

## Dimensions in mm (1 mm = 0.0394")



Input Rectifier D1-D6

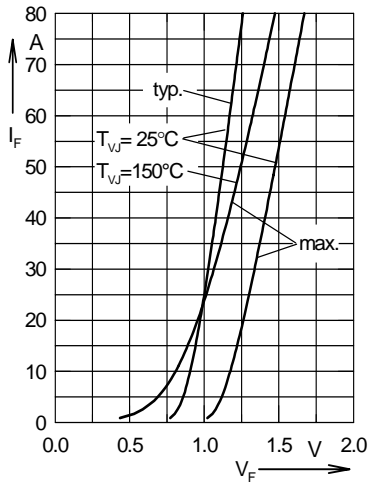


Fig. 1 Forward current versus voltage drop per rectifier diode

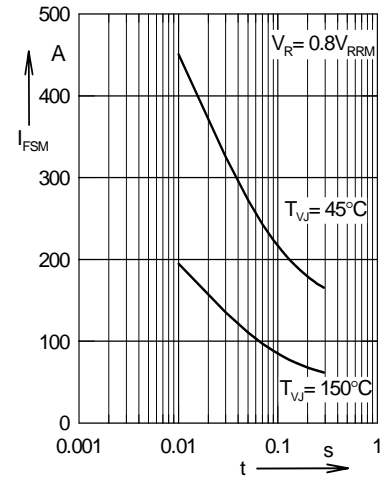


Fig. 2 Surge overload current per rectifier diode

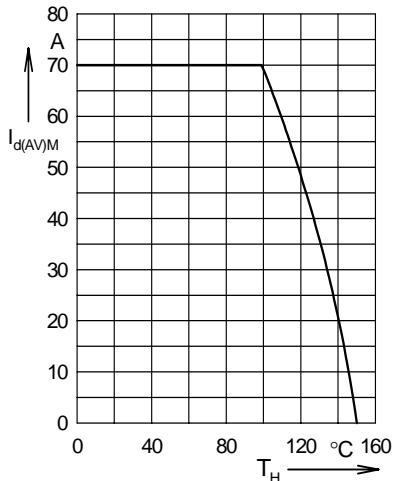


Fig. 3 Maximum forward current versus heatsink temperature (Rectifier bridge)

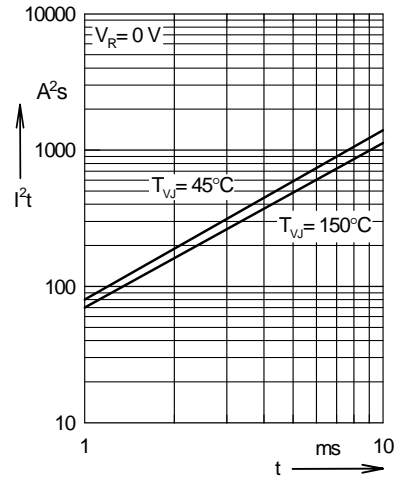


Fig. 4 I<sup>2</sup>t versus time per rectifier diode

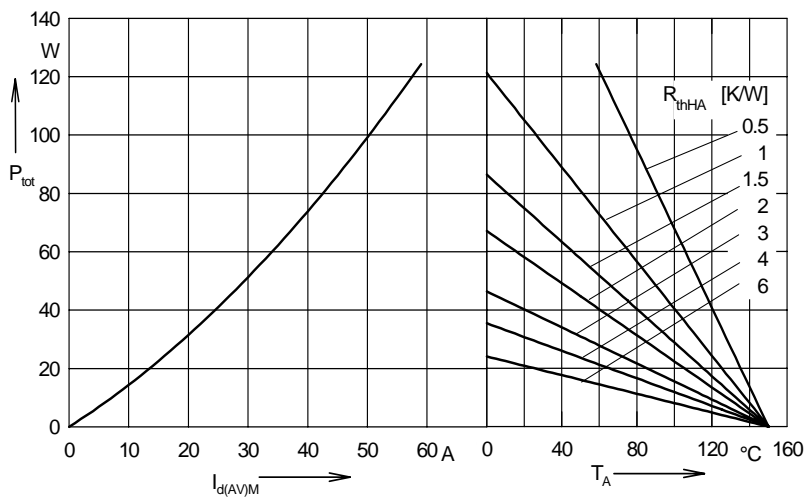


Fig. 5 Power dissipation versus direct output current and ambient temperature (Rectifier bridge)

Note:  
transient thermal impedance  
see next page

Chopper T - D

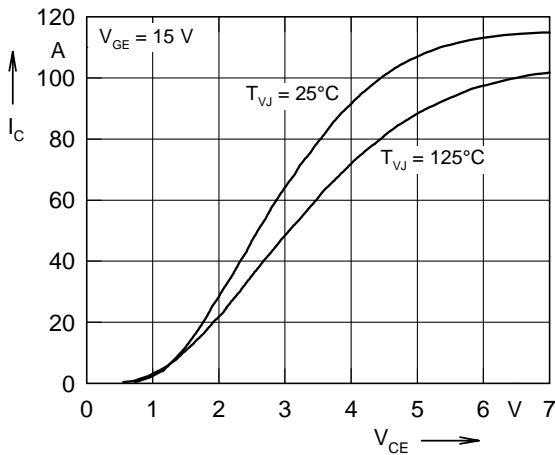


Fig. 6 Typ. IGBT output characteristics

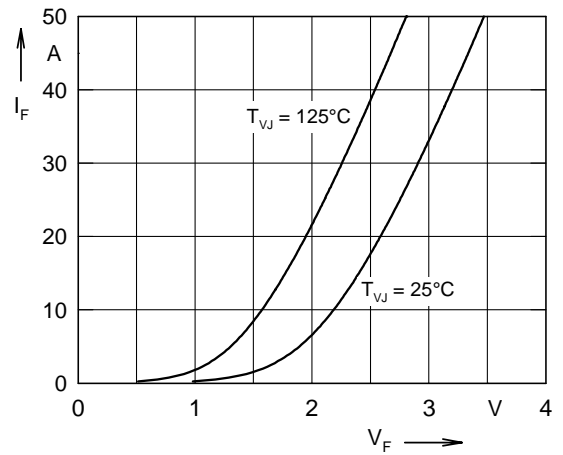


Fig. 7 Typ. forward characteristics of free wheeling diode

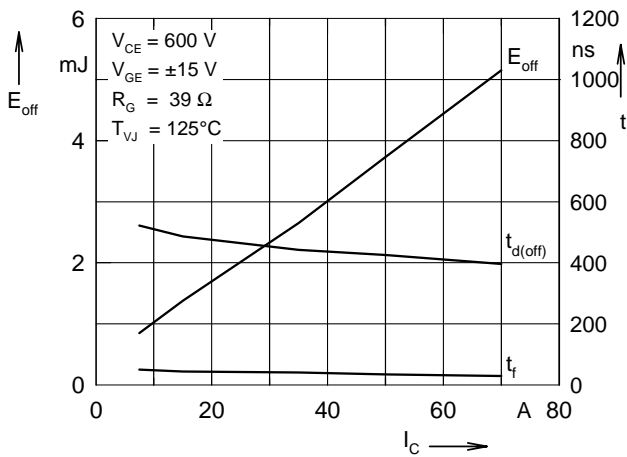


Fig. 8 Typ. IGBT turn off energy and switching times versus collector current

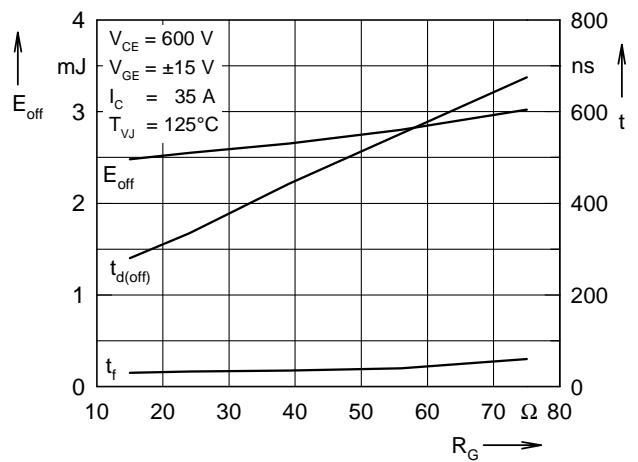


Fig. 9 Typ. IGBT turn off energy and switching times versus gate resistor

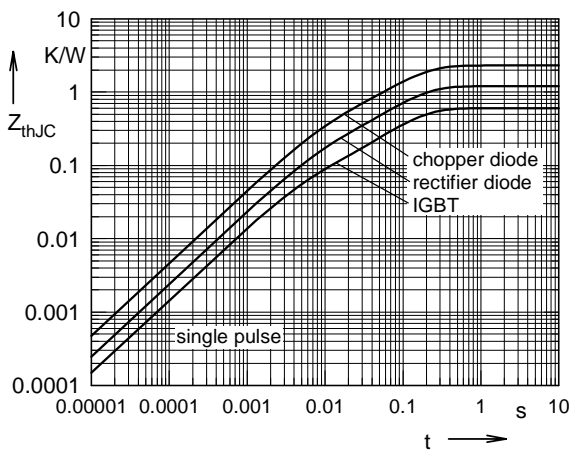


Fig. 10 Typ. transient thermal impedance

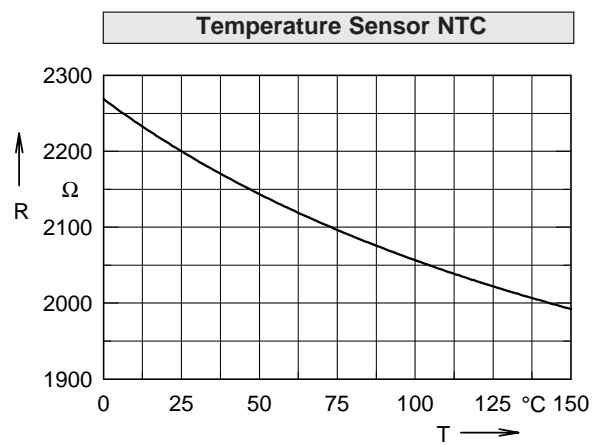


Fig. 11 Typ. thermistorresistance versus temperature

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